

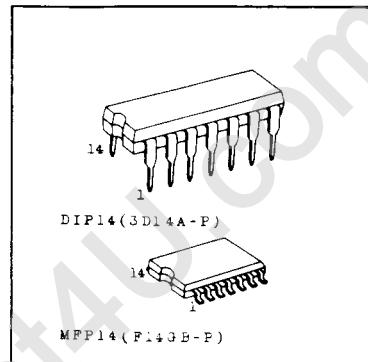
**C²MOS DIGITAL INTEGRATED CIRCUIT
SILICON MONOLITHIC**
**TC40H242P/F
TC40H243P/F**

QUAD BIDIRECTIONAL BUS BUFFER

**TC40H242 INVERTED 3-STATE OUTPUTS
TC40H243 NONINVERTED 3-STATE OUTPUTS**

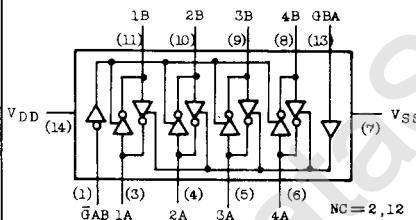
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V _{DD}	V _{SS} -0.5 ~ V _{SS} +10	V
Input Voltage	V _{IN}	V _{SS} -0.5 ~ V _{DD} +0.5	V
Output Voltage	V _{OUT}	V _{SS} -0.5 ~ V _{SS} +0.5	V
Input Current	I _{IN}	±10	mA
Power Dissipation	P _D	300(DIP)/180(MFP)	mW
Storage Temperature	T _{STG}	-65 ~ 150	°C
Lead Temp./Time	T _{SOL}	260°C • 10 sec	



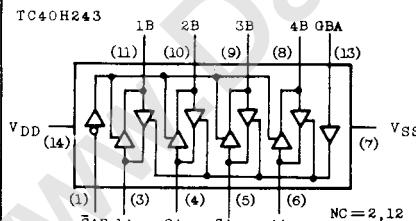
PIN CONNECTION AND TRUTH TABLE

TC40H242



CONTROL	INPUTS	DATA PORT STATUS	
		A	B
—	—	INPUT	L OUTPUT H
L	L		H L
H	H	OUTPUT	L INPUT H
			H L
L	H		Don't use
H	L		High Impedance

TC40H243



CONTROL	INPUTS	DATA PORT STATUS	
		A	B
—	—	INPUT	L OUTPUT L
L	L		H
H	H	OUTPUT	L INPUT H
			H
L	H		Don't use
H	L		High Impedance

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{DD}	—	2.0	—	8.0	V
Input Voltage	V _{IN}	—	0	—	V _{DD}	V
Operating Temperature	T _{OPR}	—	-40	—	85	°C

TC40H242P/F

TC40H243P/F

ELECTRICAL CHARACTERISTICS ($V_{SS}=0V$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V_{DD} (V)	-40°C		25°C			85°C		UNIT
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
High Level Output Voltage	V_{OH}	$ I_{OUT} < 1\mu A$ $V_{IN}=V_{SS}, V_{DD}$	5	4.95	-	4.95	5.0	-	4.95	-	V
Low Level Output Voltage	V_{OL}	$ I_{OUT} < 1\mu A$ $V_{IN}=V_{SS}, V_{DD}$	5	-	0.05	-	0.0	0.05	-	0.05	
High Level Output Current	I_{OH}	$V_{OUT}=4.6V$ $V_{IN}=V_{SS}, V_{DD}$	5	-0.95	-	-0.88	-	-	-0.8	-	mA
High Level Output Current	I_{OL}	$V_{OUT}=0.4V$ $V_{IN}=V_{SS}, V_{DD}$	5	4.7	-	4.4	-	-	4.0	-	
Input Voltage	"H" Level	V_{IH}	$ I_{OUT} < 1\mu A$ $V_{OUT}=0.5V$	5	4.0	-	4.0	-	-	4.0	-
	"L" Level	V_{IL}	$V_{OUT}=4.5V$	5	-	1.0	-	-	1.0	-	1.0
Input Current	"H" Level	I_{IH}	$V_{IN}=8.0V$	8	-	0.5	-	10^{-4}	0.5	-	5
	"L" Level	I_{IL}	$V_{IN}=0.0V$	8	-	-0.5	-	-10^{-4}	-0.5	-	-5
Output Disable Current	"H" Level	I_{DH}	$V_{DH}=8.0V$	8	-	0.5	-	10^{-4}	0.5	-	5
	"L" Level	I_{DL}	$V_{DL}=0.0V$	8	-	-0.5	-	-10^{-4}	-0.5	-	-5
Quiescent Supply Current	I_{DD}	$*V_{IN}=V_{SS}, V_{DD}$	5	-	5.0	-	0.005	5.0	-	25	μA

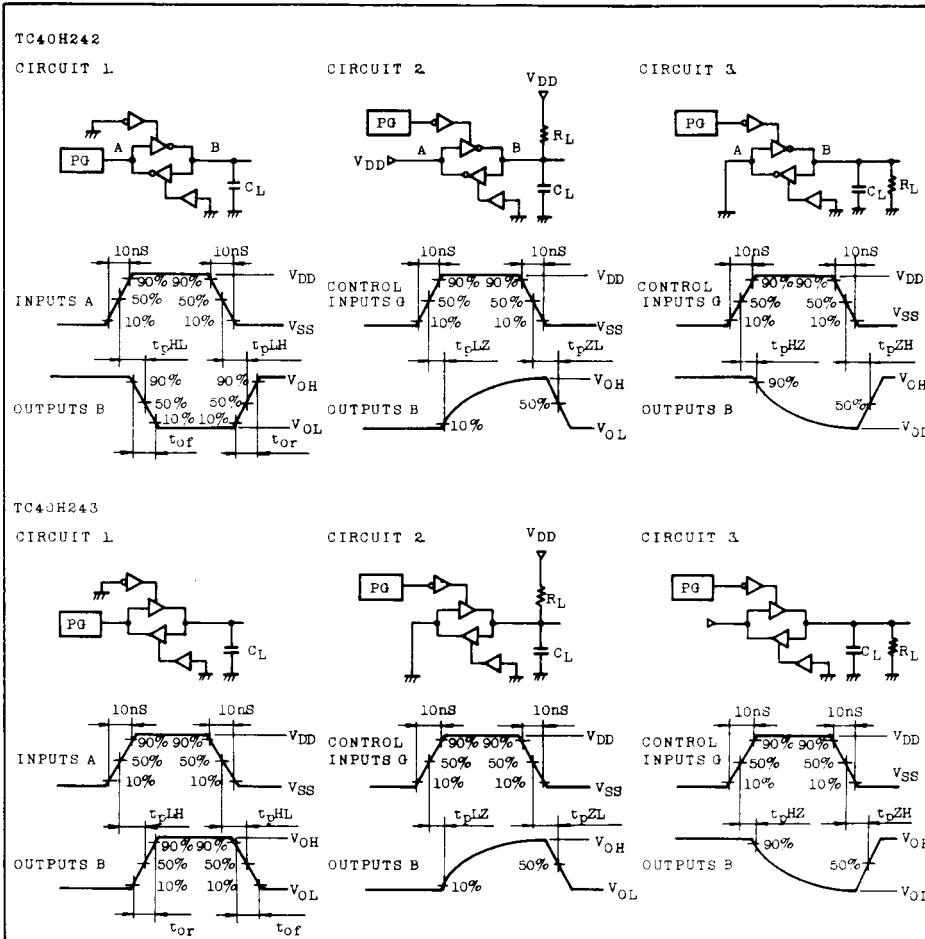
*All valid input combinations.

SWITCHING CHARACTERISTICS ($T_a=25^\circ C$, $V_{SS}=0V$, $V_{DD}=5V$, $C_L=50pF$, $R_L=1k\Omega$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	TC40H242			TC40H243			UNIT	
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Output Rise Time	t_{or}		-	15	30	-	15	30	ns	
Output Fall Time	t_{of}		-	14	30	-	14	30		
Propagation Delay Time	t_{pLH}	Fig. 1	-	23	35	-	22	35	ns	
	t_{pHL}		-	26	39	-	25	39		
Output Disable Time	"H" Level	t_{pHZ}	Fig. 3	-	32	48	-	32	48	ns
	"L" Level	t_{pLZ}	Fig. 2	-	29	44	-	29	44	
Output Enable Time	"H" Level	t_{pZH}	Fig. 3	-	29	44	-	29	44	
	"L" Level	t_{pZL}	Fig. 2	-	32	48	-	32	48	
Input Capacitance	C_{IN}		-	5		-	5		pF	
Output Capacitance	C_{OUT}		-	19		-	19		pF	

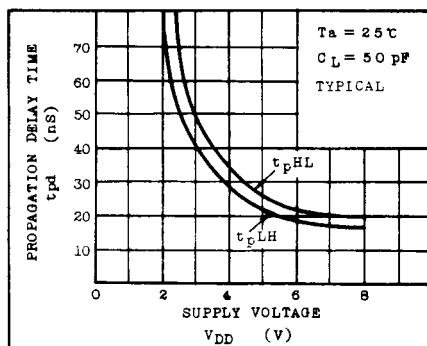
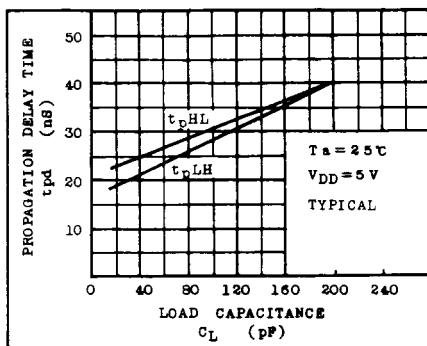
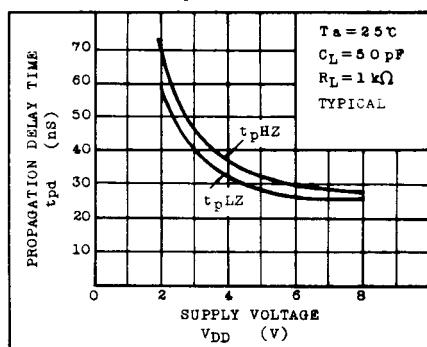
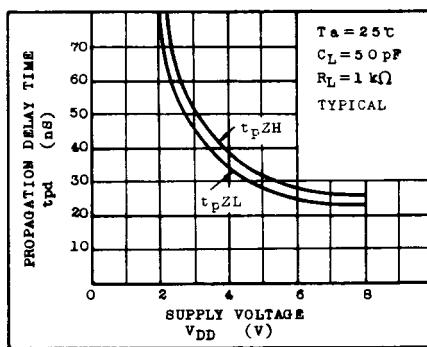
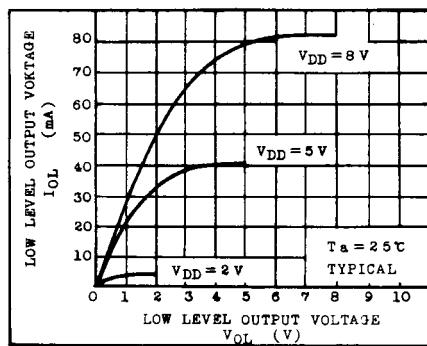
TC40H242P/F TC40H243P/F

SWITCHING TIME TEST CIRCUIT AND WAVEFORM



TC40H242P/F

TC40H243P/F

 $t_{pd} - V_{DD}$  $t_{pd} - C_L$  $t_{pd} - V_{DD}$  $t_{pd} - V_{DD}$  $I_{OL} - V_{OL}$  $I_{OH} - (V_{DD} - V_{OH})$ 